

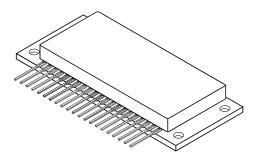
THREE PHASE BRIDGE **3017**

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(315) 701-6751

FEATURES:

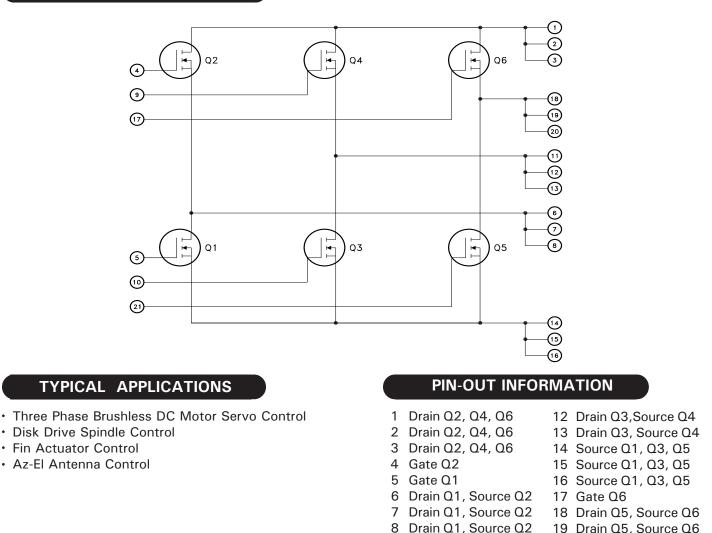
- All N-Channel Mosfets
- · Isolated Package for Direct Heat Sinking, Excellent Thermal Conductivity
- Avalanche Rated Devices
- Interfaces with Most Brushless Motor Drive IC's
- 200 Volt, 30 Amp Full Three Phase Bridge at 25°C



DESCRIPTION:

The MSK 3017 is an all N-Channel three phase power MOSFET Bridge Circuit. Packaged in a space efficient isolated ceramic tab power SIP that allows for direct heat sinking, the MSK 3017 can be interfaced with a wide array of brushless motor drive IC's. The MSK 3017 uses M.S Kennedy's proven power hybrid technology to produce a cost effective high performance circuit for use in today's sophisticated servo motor and disk drive systems.

EQUIVALENT SCHEMATIC



20 Drain Q5, Source Q6

21 Gate Q5

9 Gate Q4

10 Gate Q3

11 Drain Q3, Source Q4

ABSOLUTE MAXIMUM RATINGS

Drain to Source Voltage 200V MAX
Drain to Gate Voltage
$(RGS = 1M\Omega)$
Gate to Source Voltage
(Continuous) ± 20V MAX
Continuous Current
Pulsed Current
Thermal Resistance
(Junction to Case)@25°C 1.0°C/W
Thermal Resistance
(Junction to Case)@125°C 1.6°C/W

Single Pulse Avalanche Energy	
TJ Junction Temperature	+ 150°C MAX
Tst Storage Temperature	
Tc Case Operating Temperature Range -	55°C to +125°C
TLD Lead Temperature Range	
(10 Seconds Lead Only)	200°C MAX

ELECTRICAL SPECIFICATIONS

Parameter	Test Conditions ④	MSK3017			
		Min.	Тур.	Max.	Units
Drain-Source Breakdown Voltage	Vgs=0 ID=0.25mA	200	-	-	V
Drain-Source Leakage Current	V _{DS} = 200V V _{GS} = 0V	-	-	250	μΑ
Gate-Source Leakage Current	$V_{GS} = \pm 20V V_{DS} = 0$	-	-	±100	nA
Gate-Source Threshold Voltage	$V_{DS} = V_{GS}$ $I_D = 250 \mu A$	2.0	-	4.0	V
Drain-Source On Resistance ②	$V_{GS} = 10V ID = 30A$	-	-	0.09	Ω
Drain-Source On Resistance ③	$V_{GS} = 10V$ $I_D = 30A$	-	-	0.06	Ω
Forward Transconductance ①	$V_{DS} = 50V$ $I_D = 30A$	24	-	-	S
Total Gate Charge ①	ID = 30A	-	-	230	nC
Gate-Source Charge ①	$V_{DS} = 160V$	-	-	42	nC
Gate-Drain Charge ①	$V_{GS} = 10V$	-	-	110	nC
Turn-On Delay Time ①	$V_{DD} = 100V$	-	23	-	nS
Rise Time ①	ID = 30A	-	120	-	nS
Turn-Off Delay Time ①	$R_G = 4.3\Omega$	-	100	-	nS
Fall Time ①	$R_D = 2.1\Omega$	-	94	-	nS
Input Capacitance ①	V _{GS} = 0V	-	5200	-	pF
Output Capacitance ①	$V_{DS} = 25V$	-	1200	-	pF
Reverse Transfer Capacitance ①	f = 1MHz	-	310	-	pF
Body Diode		•			
Forward On Voltage ①	Is = 30 A VGs = 0V	-	1.8	-	V
Reverse Recovery Time 1	$Is = 30 A di/dt = 100 A/\mu S$	-	390	590	nS
Reverse Recovery Charge ①		-	4.8	7.2	μΟ

NOTES:

This parameter is guaranteed by design but need not be tested. Typical parameters are representative of actual device performance but are for reference only.
Resistance as seen at package pins.
Resistance for die only; use for thermal calculations.
TA = 25 °C unless otherwise specified.

APPLICATION NOTES

BRIDGE DRIVE CONSIDERATIONS

It is important that the logic used to turn ON and OFF the various transistors allow sufficient "dead time" between a high side transistor and its low side transistor to make sure that at no time are they both ON. When they are, this is called "shoot-through", and it places a momentary short across the power supply. This overly stresses the transistors and causes excessive noise as well. See Figure 1.

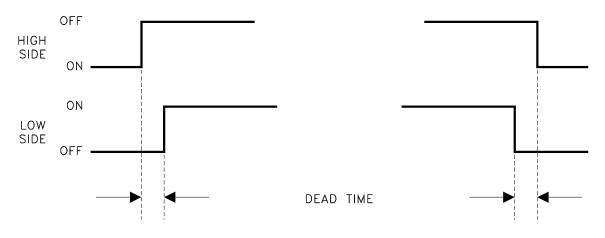
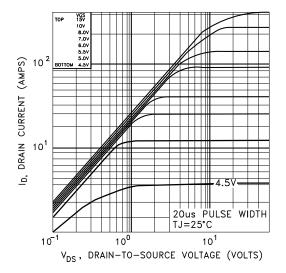


Figure 1

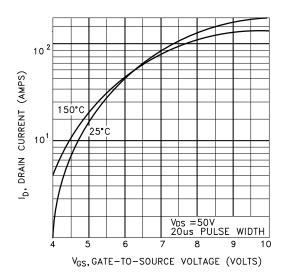
This deadtime should allow for the turn on and turn off time of the transistors, especially when slowing them down with gate resistors. This situation will be present when switching motor direction, or when sophisticated timing schemes are used for servo systems such as locked antiphase PWM'ing for high bandwidth operation.

TYPICAL PERFORMANCE CURVES

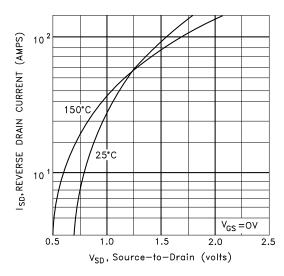
TYPICAL OUTPUT CHARACTERISTICS $T_c = 25^{\circ}C$



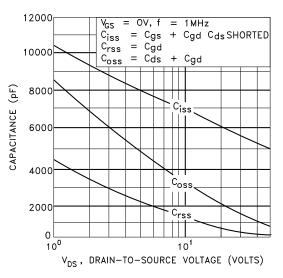




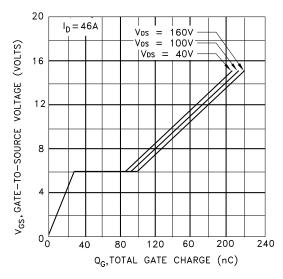
TYPICAL SOURCE-DRAIN DIODE FORWARD VOLTAGE



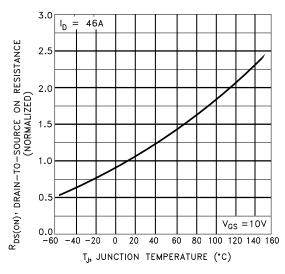
TYPICAL CAPACITANCE vs DRAIN TO SOURCE VOLTAGE



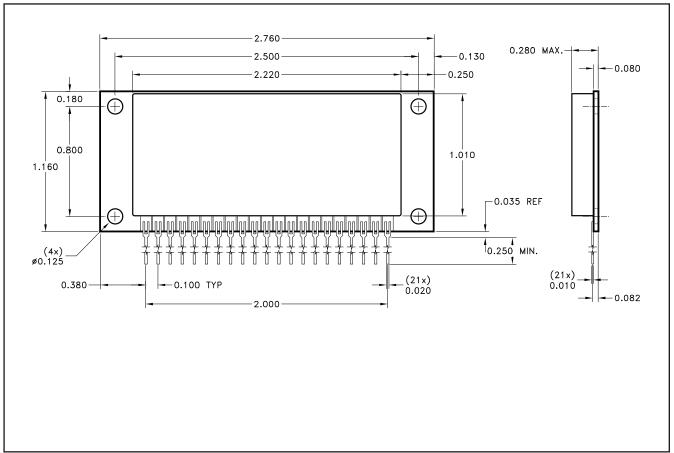








MECHANICAL SPECIFICATIONS



ALL DIMENSIONS ARE ±0.010 INCHES UNLESS OTHERWISE LABELED.

ORDERING INFORMATION

Part Number	Screening Level
MSK 3017	Industrial

M.S. Kennedy Corp. 4707 Dey Road, Liverpool, New York 13088 Phone (315) 701-6751 FAX (315) 701-6752 www.mskennedy.com

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